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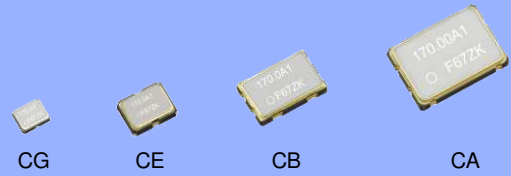


CRYSTAL OSCILLATOR (Programmable)
OUTPUT: CMOS**SG-8101** series**NEW**

- Frequency range : 0.67 MHz ~ 170 MHz (1 ppm Step)
- Supply voltage : 1.62 V ~ 3.63 V
- Function : Output enable (OE) or Standby (ST)
- Frequency tolerance, operating temperature:
 - ±15 ppm (-40 °C ~ +85 °C)
 - ±20 ppm, ±50 ppm (-40 °C ~ +105 °C)
- Package : 2.5 x 2.0, 3.2 x 2.5, 5.0 x 3.2, 7.0 x 5.0 (mm)
- PLL technology to enable short lead time
- Available field oscillator programmer "SG-Writer II"



Product Number (please contact us)
 SG-8101CA: X1G005191xxxx00
 SG-8101CB: X1G005201xxxx00
 SG-8101CE: X1G005211xxxx00
 SG-8101CG: X1G005181xxxx00



Specifications (characteristics)

Item	Symbol	Specifications				Conditions/Remarks																																														
Supply voltage	V _{CC}	1.80 V Typ.		2.50 V Typ.	3.30 V Typ.	-																																														
		1.62 V ~ 1.98 V	1.98 V ~ 2.20 V	2.20 V ~ 2.80 V	2.70 V ~ 3.63 V																																															
Output frequency range	f _o	0.67 MHz ~ 170 MHz																																																		
Storage temperature	T _{stg}	-40 °C ~ +125 °C				Storage as single product.																																														
Operating temperature	T _{use}	-40 °C ~ +85 °C				-																																														
		-40 °C ~ +105 °C				-																																														
Frequency tolerance ^{*1}	f _{tol}	B: ±15 × 10 ⁻⁶				T _{use} = -40 °C ~ +85 °C																																														
		C: ±20 × 10 ⁻⁶				T _{use} = -40 °C ~ +105 °C																																														
		J: ±50 × 10 ⁻⁶				T _{use} = -40 °C ~ +105 °C																																														
Current consumption	I _{CC}	3.2 mA Max.	3.3 mA Max.	3.4 mA Max.	3.5 mA Max.	T _{use} = +105 °C	No load, f _o = 20 MHz																																													
		2.7 mA Typ.		2.9 mA Typ.	3.0 mA Typ.	T _{use} = +25 °C																																														
		5.5 mA Max.	5.8 mA Max.	6.7 mA Max.	8.1 mA Max.	T _{use} = +105 °C																																														
Output disable current	I _{dis}	4.7 mA Typ.		5.7 mA Typ.	6.8 mA Typ.	T _{use} = +25 °C	No load, f _o = 170 MHz																																													
		3.2 mA Max.	3.2 mA Max.	3.3 mA Max.	3.5 mA Max.	OE = GND, f _o = 170 MHz																																														
Standby current	I _{std}	0.9 μA Max.	1.0 μA Max.	1.5 μA Max.	2.5 μA Max.	T _{use} = +105 °C	ST = GND																																													
		0.3 μA Typ.	0.4 μA Typ.	0.5 μA Typ.	1.1 μA Typ.	T _{use} = +25 °C																																														
Symmetry	SYM	45 % ~ 55 %				50 % V _{CC} Level																																														
Output voltage (DC characteristics)	V _{OH}	90 % V _{CC} Min.				<table border="1"> <thead> <tr> <th colspan="6">I_{OH}/I_{OL} Conditions [mA]</th> </tr> <tr> <th>Rise/Fall time</th> <th>V_{CC}</th> <th>*A</th> <th>*B</th> <th>*C</th> <th>*D</th> </tr> </thead> <tbody> <tr> <td rowspan="2">Default (f_o > 40 MHz), Fast</td> <td>I_{OH}</td> <td>-2.5</td> <td>-3.5</td> <td>-4.0</td> <td>-5.0</td> </tr> <tr> <td>I_{OL}</td> <td>2.5</td> <td>3.5</td> <td>4.0</td> <td>5.0</td> </tr> <tr> <td rowspan="2">Default (f_o ≤ 40 MHz)</td> <td>I_{OH}</td> <td>-1.5</td> <td>-2.0</td> <td>-2.5</td> <td>-3.0</td> </tr> <tr> <td>I_{OL}</td> <td>1.5</td> <td>2.0</td> <td>2.5</td> <td>3.0</td> </tr> <tr> <td rowspan="2">Slow</td> <td>I_{OH}</td> <td>-1.0</td> <td>-1.5</td> <td>-2.0</td> <td>-2.5</td> </tr> <tr> <td>I_{OL}</td> <td>1.0</td> <td>1.5</td> <td>2.0</td> <td>2.5</td> </tr> </tbody> </table>		I _{OH} /I _{OL} Conditions [mA]						Rise/Fall time	V _{CC}	*A	*B	*C	*D	Default (f _o > 40 MHz), Fast	I _{OH}	-2.5	-3.5	-4.0	-5.0	I _{OL}	2.5	3.5	4.0	5.0	Default (f _o ≤ 40 MHz)	I _{OH}	-1.5	-2.0	-2.5	-3.0	I _{OL}	1.5	2.0	2.5	3.0	Slow	I _{OH}	-1.0	-1.5	-2.0	-2.5	I _{OL}	1.0	1.5	2.0	2.5
	I _{OH} /I _{OL} Conditions [mA]																																																			
Rise/Fall time	V _{CC}	*A	*B	*C	*D																																															
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Slow	I _{OH}	-1.0	-1.5	-2.0	-2.5																																															
	I _{OL}	1.0	1.5	2.0	2.5																																															
V _{OL}	10 % V _{CC} Max.																																																			
Output load condition	L _{CMOS}	15 pF Max.				-																																														
Input voltage	V _{IH}	70 % V _{CC} Min.				OE or ST																																														
	V _{IL}	30 % V _{CC} Max.																																																		
Rise and Fall time	Default Fast Slow	tr/tf	3.0 ns Max.		f _o > 40 MHz		20 % - 80 % V _{CC} , L _{CMOS} = 15 pF																																													
			6.0 ns Max.		f _o ≤ 40 MHz																																															
			3.0 ns Max.		f _o = 0.67 MHz ~ 170 MHz																																															
			10.0 ns Max.		f _o = 0.67 MHz ~ 20 MHz																																															
Disable Time	t _{stp}	1 μs Max.		Measured from the time OE or ST pin crosses 30 % V _{CC}																																																
Enable Time	t _{sta}	1 μs Max.		Measured from the time OE pin crosses 70 % V _{CC}																																																
Resume Time	t _{res}	3 ms Max.		Measured from the time ST pin crosses 70 % V _{CC}																																																
Start-up time	t _{str}	3 ms Max.		Measured from the time V _{CC} reaches its rated minimum value, 1.62 V																																																
Frequency aging	f _{aging}	This is included in frequency tolerance specification.				+25 °C, first year																																														

*1 Frequency tolerance includes initial frequency tolerance, temperature variation, supply voltage variation, reflow drift, load drift and aging (+25 °C, 1 year).

Pin description

Pin	Name	I/O type	Function	
1	OE	Input	Output enable	High: Specified frequency output from OUT pin Low: Out pin is low (weak pull down), only output driver is disabled.
	ST	Input	Standby	High: Specified frequency output from OUT pin Low: Out pin is low (weak pull down), Device goes to standby mode. Supply current reduces to the least as I _{std} .
2	GND	Power	Ground	
3	OUT	Output	Clock output	
4	V _{CC}	Power	Power supply	



Product Name

SG-8101CG 170.000000MHz T C H P A

① ② ③ ④ ⑤ ⑥ ⑦ ⑧

- ① Model, ② Package type,
- ③ Frequency, ④ Supply voltage,
- ⑤ Frequency tolerance, ⑥ Operating temperature,
- ⑦ Function, ⑧ Rise/Fall time

② Package type
CA: 7.0 mm x 5.0 mm
CB: 5.0 mm x 3.2 mm
CE: 3.2 mm x 2.5 mm
CG: 2.5 mm x 2.0 mm

④ Supply voltage
T: 1.8 V ~ 3.3 V Typ.

⑥ Operating temperature
G: -40 °C ~ +85 °C
H: -40 °C ~ +105 °C

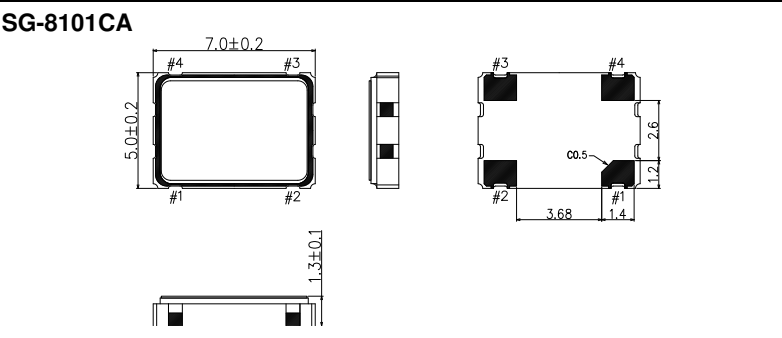
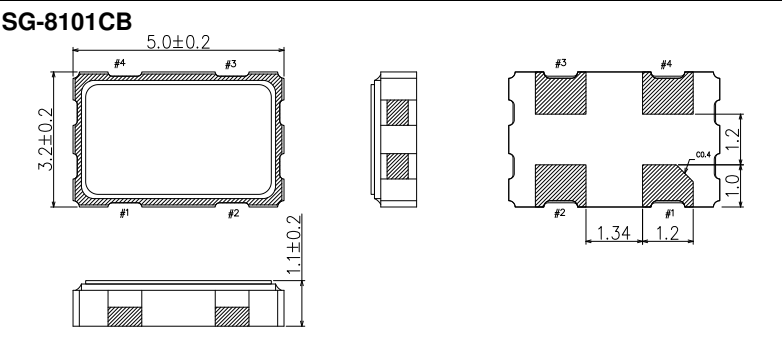
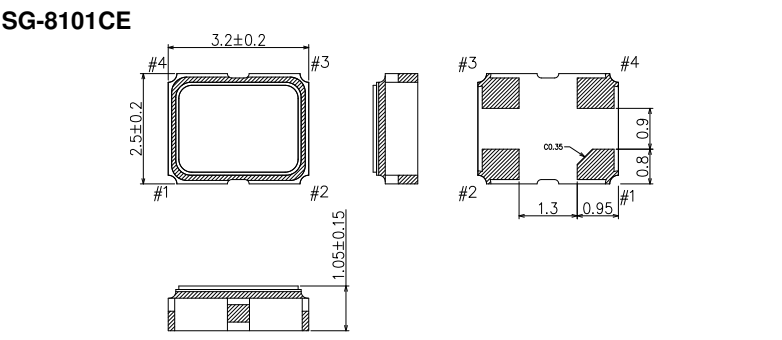
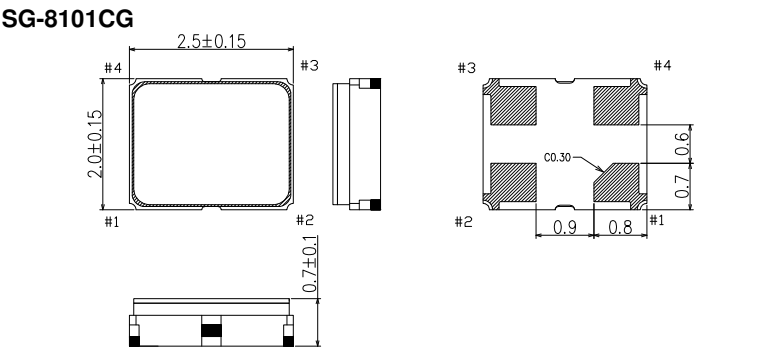
⑧ Rise/Fall time
A: Default
B: Fast
C: Slow

⑤ Frequency tolerance
B: 15 x 10 ⁻⁶
C: 20 x 10 ⁻⁶
J: 50 x 10 ⁻⁶

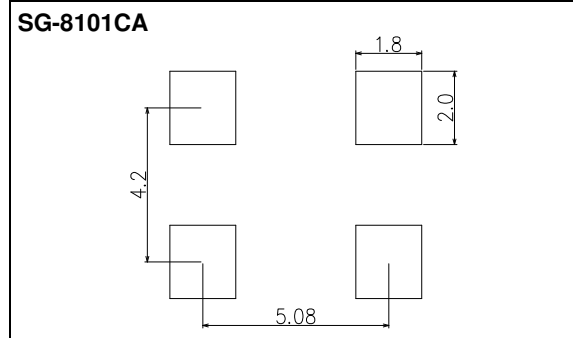
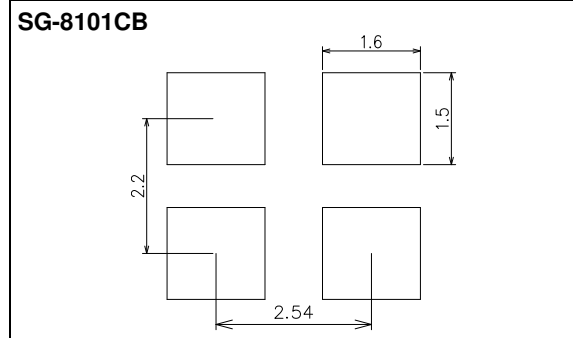
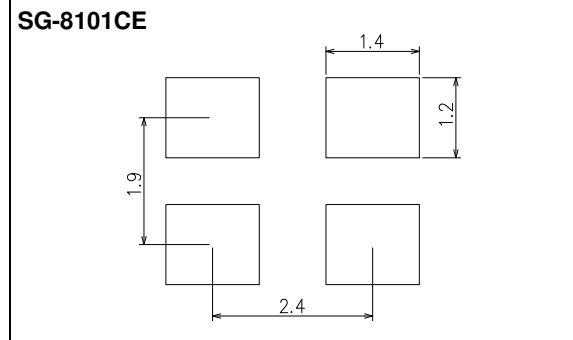
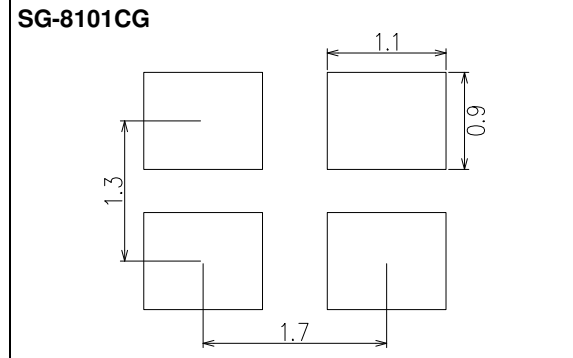
⑦ Function
P: Output Enable
S: Standby

Available combination	CA: 7.0 mm x 5.0 mm			CB: 5.0 mm x 3.2 mm			CE: 3.2 mm x 2.5 mm			CG: 2.5 mm x 2.0 mm		
Frequency tolerance	B: 15 x 10 ⁻⁶	C: 20 x 10 ⁻⁶	J: 50 x 10 ⁻⁶	B: 15 x 10 ⁻⁶	C: 20 x 10 ⁻⁶	J: 50 x 10 ⁻⁶	B: 15 x 10 ⁻⁶	C: 20 x 10 ⁻⁶	J: 50 x 10 ⁻⁶	B: 15 x 10 ⁻⁶	C: 20 x 10 ⁻⁶	J: 50 x 10 ⁻⁶
Operating temperature	G: -40 °C ~ +85 °C	✓		✓			✓			✓		
	H: -40 °C ~ +105 °C		✓	✓		✓	✓		✓	✓		✓

External dimensions (Unit: mm)



Footprint (Recommended) (Unit: mm)



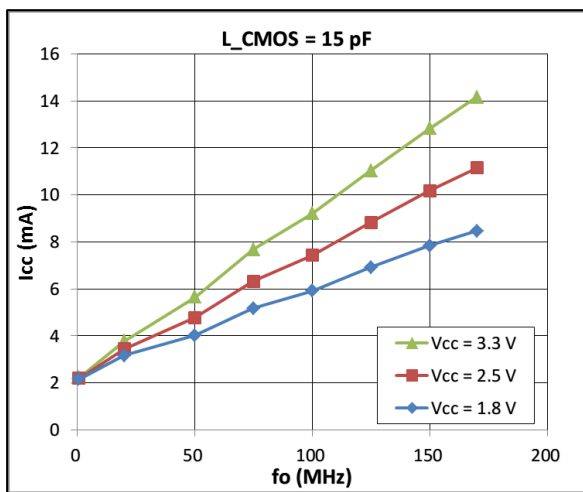
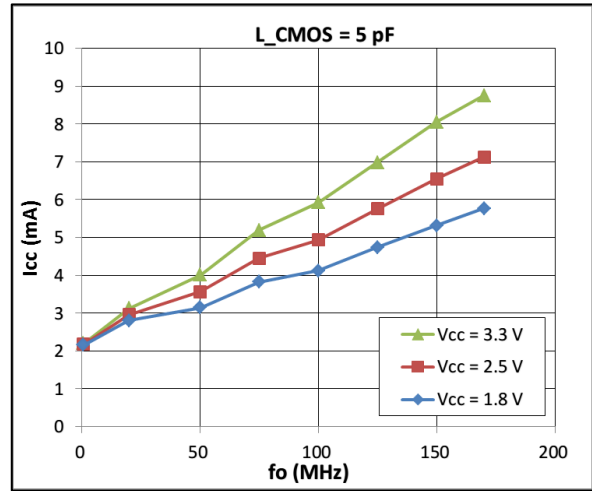
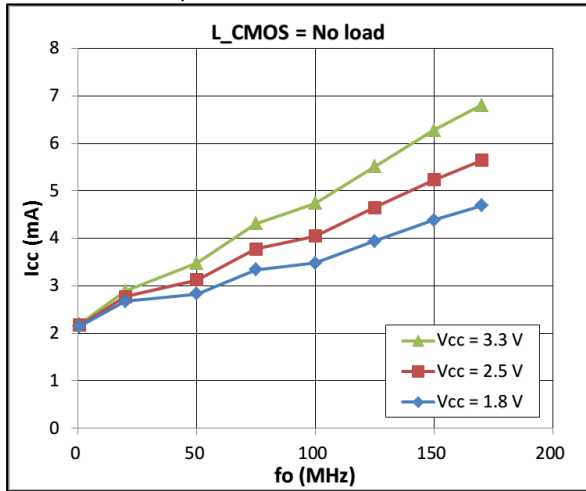
Notes:

In order to achieve optimum jitter performance, the 0.1 μF capacitor between V_{CC} and GND should be placed. It is also recommended that the capacitors are placed on the device side of the PCB, as close to the device as possible and connected together with short wiring pattern.

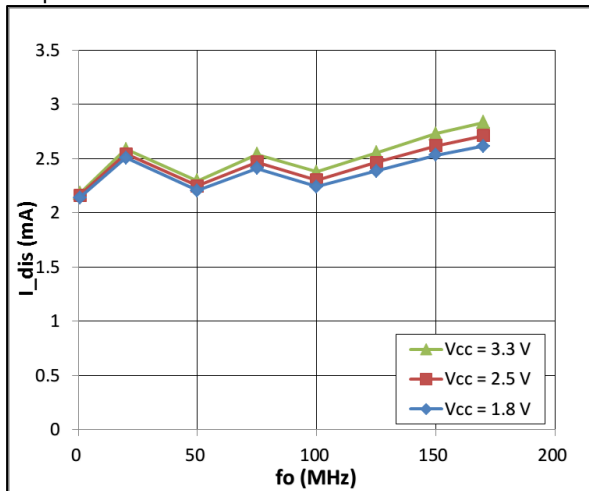


Specification Graph (Typical supplemental specification. Unless otherwise specified $T_{use} = 25\text{ }^{\circ}\text{C}$, $L_{CMOS} = 15\text{pF}$)

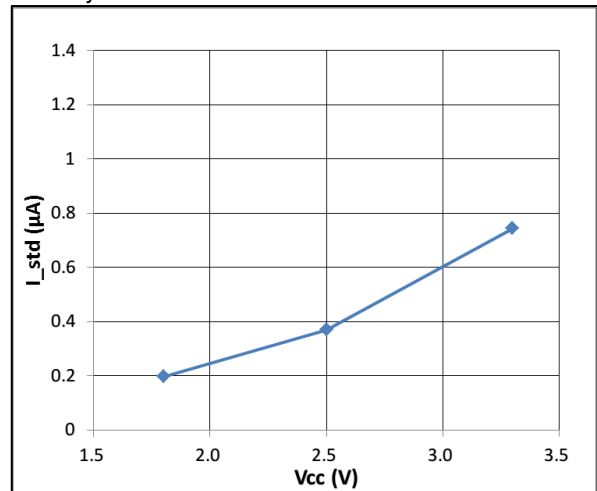
Current Consumption



Output disable current



Standby current



■ Notes:

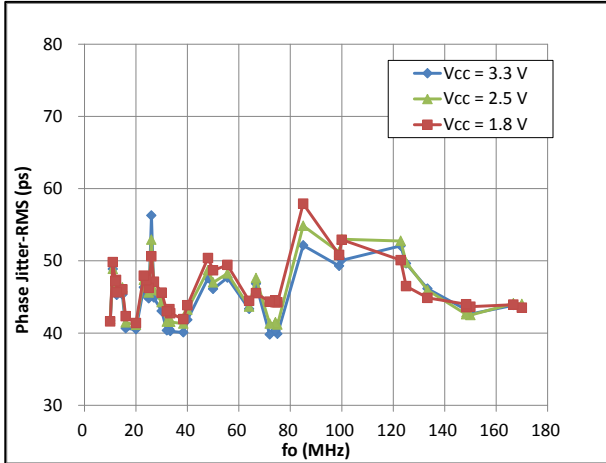




Specification Graph (Typical supplemental specification. Unless otherwise specified T_{use} = 25 °C, L_{CMOS} = 15pF)

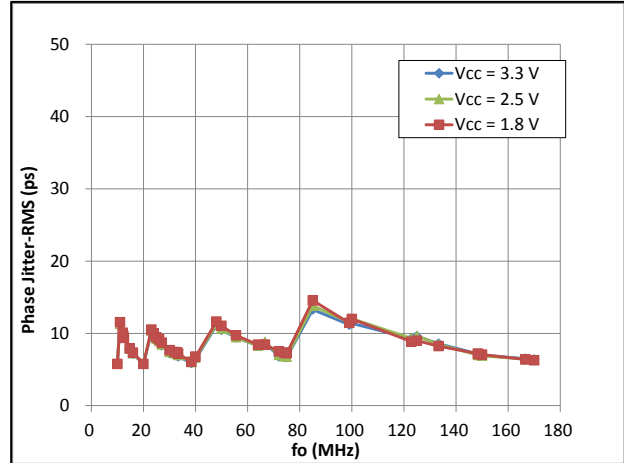
Phase Jitter RMS

(Integration bandwidth 12 k–20 MHz)

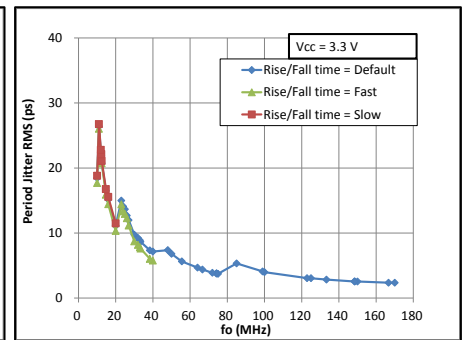
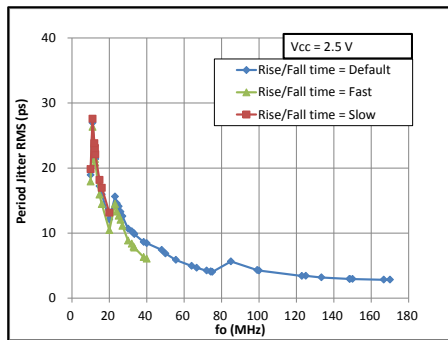
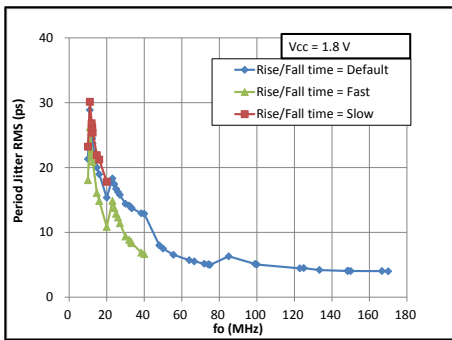


Phase Jitter RMS

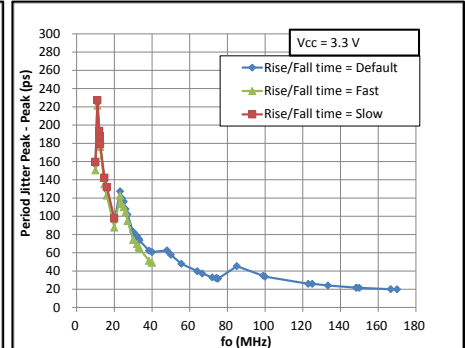
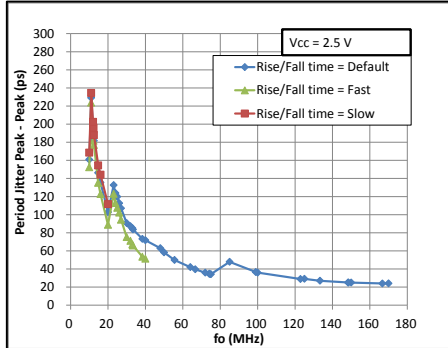
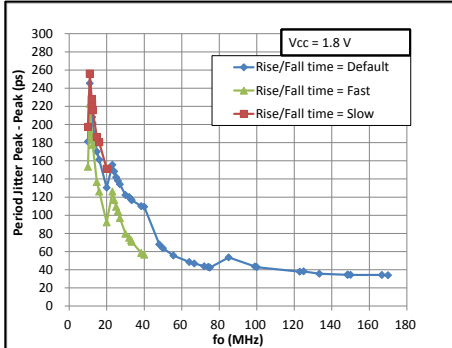
(Integration bandwidth 1.8 M–20 MHz)



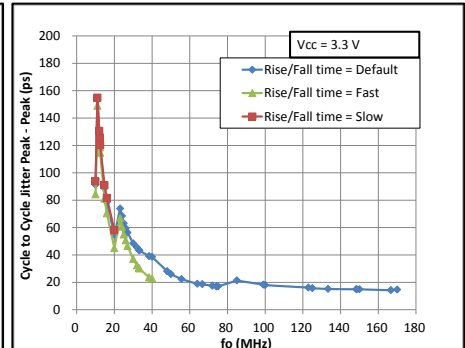
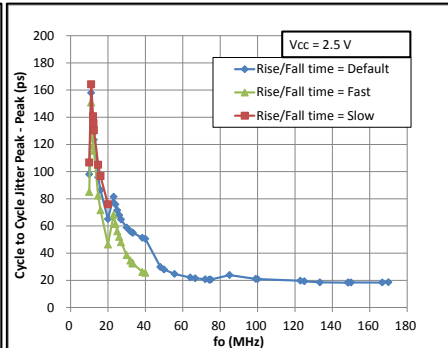
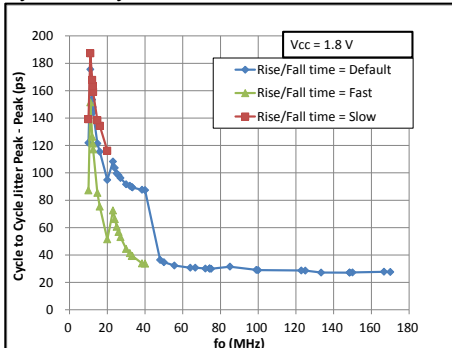
Period Jitter RMS



Period Jitter Peak-Peak



Cycle-to-Cycle Jitter Peak-Peak



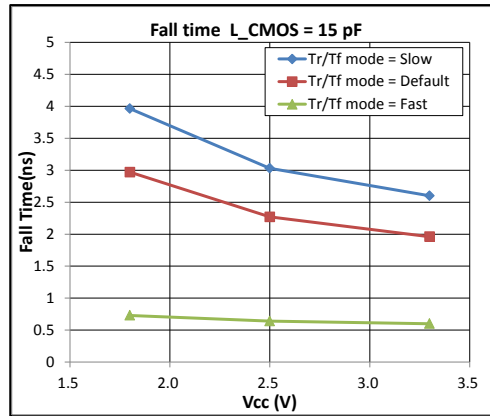
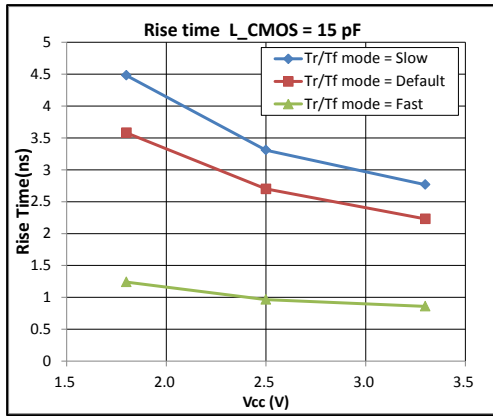
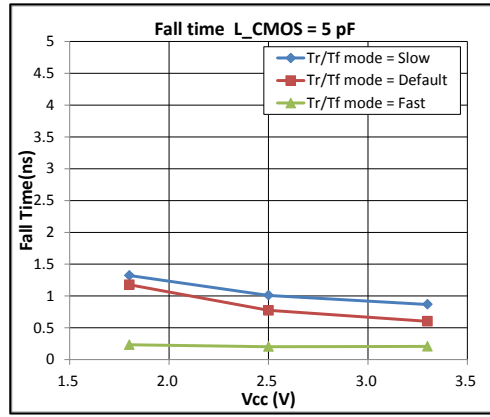
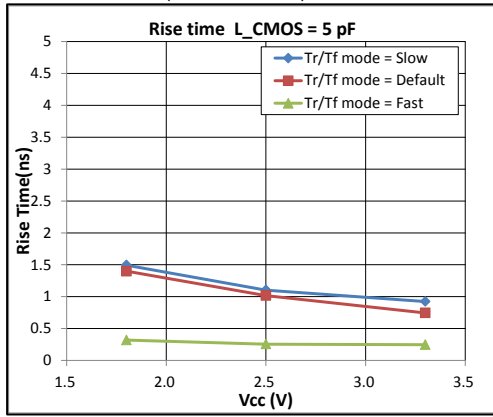
■ Notes:

Blank area for notes.



Specification Graph (Typical supplemental specification. Unless otherwise specified T_{use} = 25 °C, L_{CMOS} = 15pF)

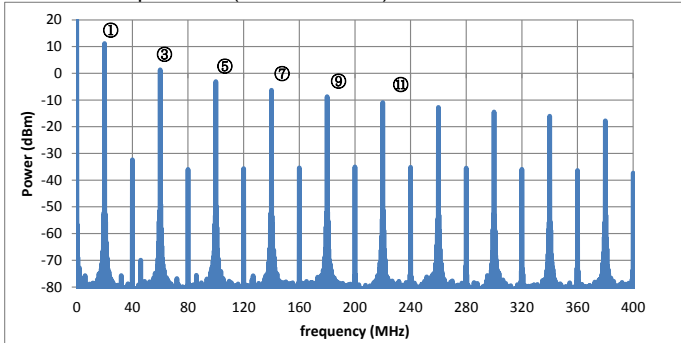
Rise/Fall Time (fo = 20 MHz)



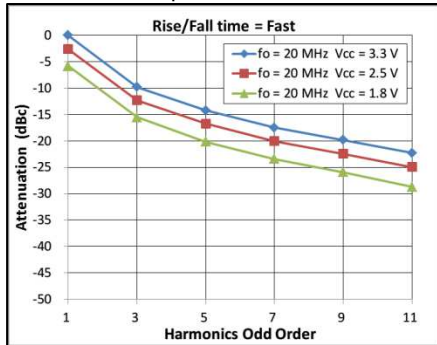
Notes:

frequency	slow	default	fast
0.67 M – 20 M	See Slow	See Default	See Fast
20 M – 40 M	-	See Default	See Fast
40 M – 170 M	-	See Fast	See Fast

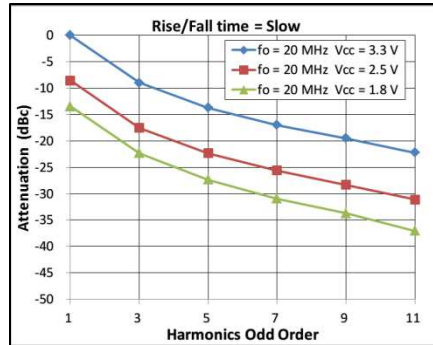
Harmonics spectrum (fo = 20 MHz)



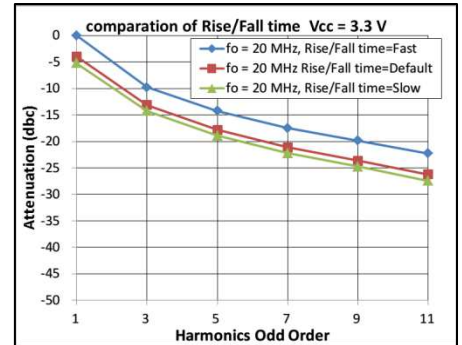
Harmonics comparison



Normalize to Vcc = 3.3V.



Normalize to Vcc = 3.3V.



Normalize to Rise/Fall time = "Fast".

Notes:



ESD Rating

Test items	Breakdown voltage
Human Body Model (HBM)	2000V
Machine Model (MM)	250V
Charged Device Model (CDM)	750V

Device Marking (Standard specification)

Model	Factory Programmed Part Marking	Field Programmable Part Marking (Blank Samples)
SG-8101CG		
SG-8101CE		
SG-8101CB		
SG-8101CA		

Simulation Model

- IBIS Model is available upon request. Please contact us.
Information Required: Oscillator operating condition (i.e. Power Supply, Rise/Fall Time, Temperature)

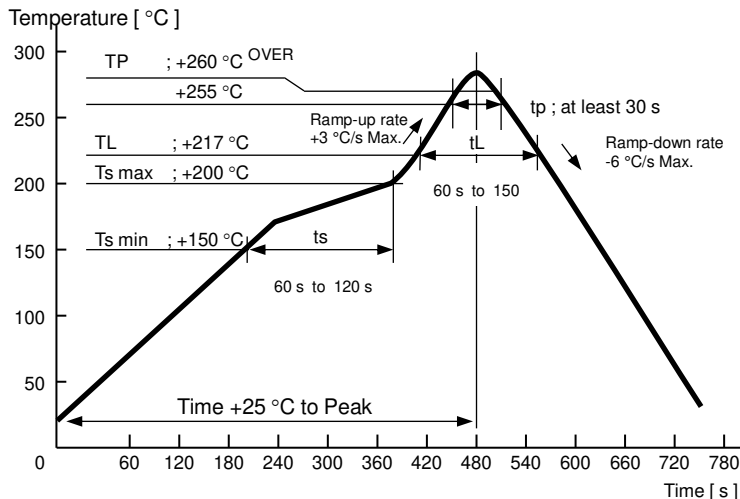


Device Material & Environmental Information

Model	Package Dimensions	# of Pins	Reference Weight (Typ.)	Terminal Material	Terminal Plating	Complies With EU RoHS	Pb Free	MSL Rating	Peak Temp. (Max)
SG-8101CG	2.5 x 2.0 x 0.7 mm	4	13 mg	W	Au	Yes	Yes	1	260°C
SG-8101CE	3.2 x 2.5 x 1.0 mm	4	25 mg	W	Au	Yes	Yes	1	260°C
SG-8101CB	5.0 x 3.2 x 1.1 mm	4	51 mg	W	Au	Yes	Yes	1	260°C
SG-8101CA	7.0 x 5.0 x 1.3 mm	4	143 mg	W	Au	Yes	Yes	1	260°C

SMD products Reflow profile(example)

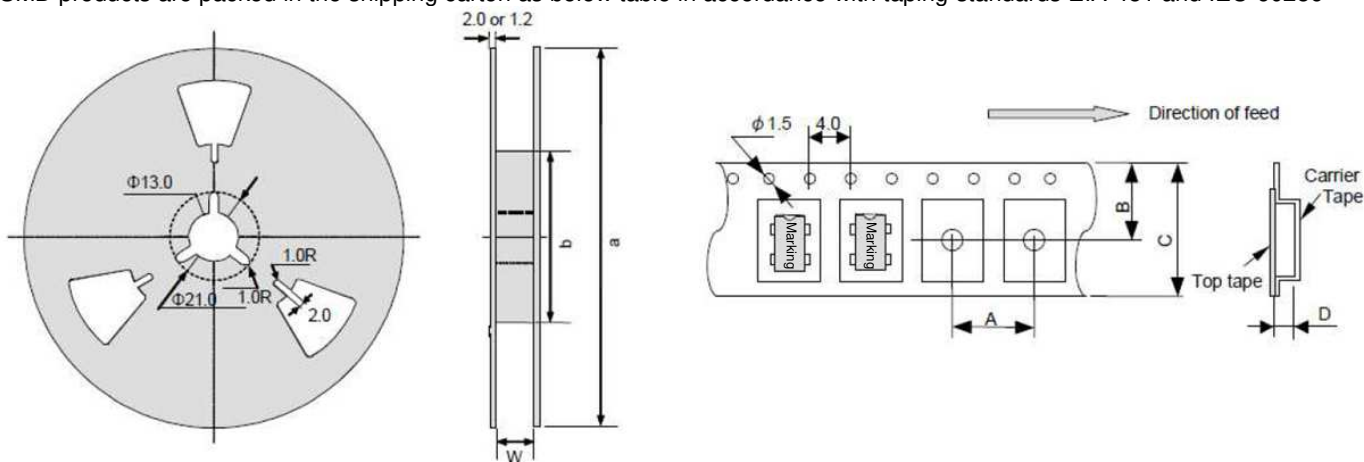
The availability of the heat resistance for reflow conditions of JEDEC-STD-020D.01 is judged individually. Please inquire.



	<ul style="list-style-type: none"> Pb free.
	<ul style="list-style-type: none"> Complies with EU RoHS directive. <ul style="list-style-type: none"> About the products without the Pb-free mark. Contains Pb in products exempted by EU RoHS directive. (Contains Pb in sealing glass, high melting temperature type solder or other.)

Standard Packing Specification

SMD products are packed in the shipping carton as below table in accordance with taping standards EIA-481 and IEC-60286



Standard Packing Quantity & Dimension(Unit mm)

Model	Quantity (pcs/Reel)	Reel Dimension			Career Tape Dimension				Direction of Feed (L= Left Direction)
		a	b	W	A	B	C	D	
SG-8101CG	3000	Φ180	Φ60	9	4	5.25	8	1.15	L
SG-8101CE	2000	Φ180	Φ60	9	4	5.25	8	1.4	L
SG-8101CB	1000	Φ180	Φ60	13	8	7.25	12	1.4	L
SG-8101CA	1000	Φ254	Φ100	17.5	8	9.25	16	2.3	L

PROMOTION OF ENVIRONMENTAL MANAGEMENT SYSTEM CONFORMING TO INTERNATIONAL STANDARDS

At Seiko Epson, all environmental initiatives operate under the Plan-Do-Check-Action (PDCA) cycle designed to achieve continuous improvements. The environmental management system (EMS) operates under the ISO 14001 environmental management standard.

All of our major manufacturing and non-manufacturing sites, in Japan and overseas, completed the acquisition of ISO 14001 certification.

ISO 14000 is an international standard for environmental management that was established by the International Standards Organization in 1996 against the background of growing concern regarding global warming, destruction of the ozone layer, and global deforestation.





WORKING FOR HIGH QUALITY

In order provide high quality and reliable products and services than meet customer needs,

Seiko Epson made early efforts towards obtaining ISO9000 series certification and has acquired ISO9001 for all business establishments in Japan and abroad. We have also acquired ISO/TS 16949 certification that is requested strongly by major automotive manufacturers as standard.

ISO/TS16949 is the international standard that added the sector-specific supplemental requirements for automotive industry based on ISO9001.

► Explanation of the mark that are using it for the catalog

	► Pb free.
	► Complies with EU RoHS directive. *About the products without the Pb-free mark. Contains Pb in products exempted by EU RoHS directive. (Contains Pb in sealing glass, high melting temperature type solder or other.)
	► Designed for automotive applications such as Car Multimedia, Body Electronics, Remote Keyless Entry etc.
	► Designed for automotive applications related to driving safety (Engine Control Unit, Air Bag, ESC etc).

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